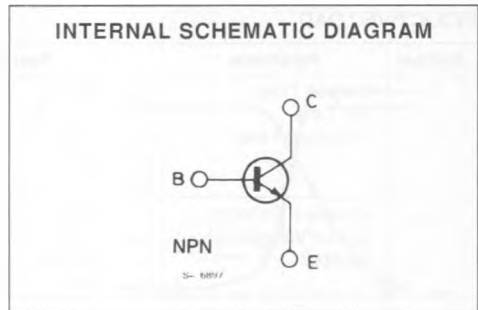
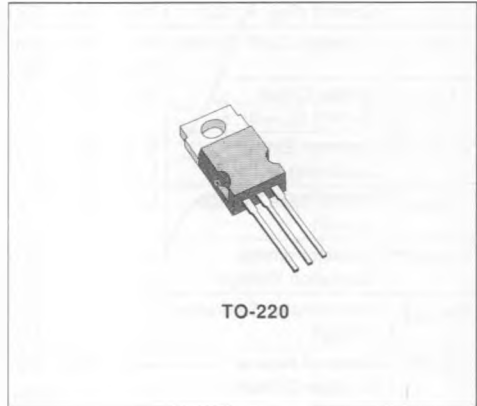


## FAST SWITCHING POWER TRANSISTOR

- SUITABLE FOR SWITCH MODE POWER SUPPLY, UPS, DC AND AC MOTOR CONTROL



### DESCRIPTION

High voltage, high speed transistor suited for use on the 220 and 380V mains.

### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CEV}$	Collector-emitter Voltage ( $V_{BE} = -1.5V$ )	850	V
$V_{CEO}$	Collector-emitter Voltage ( $I_B = 0$ )	450	V
$V_{EBO}$	Emitter-base Voltage ( $I_C = 0$ )	7	V
$I_C$	Collector Current	9	A
$I_{CM}$	Collector Peak Current	14	A
$I_B$	Base Current	3	A
$I_{BM}$	Base Peak Current	4.5	A
$P_{Tot}$	Total Dissipation at $T_C < 25^\circ C$	70	W
$T_{stg}$	Storage Temperature	- 65 to 150	$^\circ C$
$T_J$	Max. Operating Junction Temperature	150	$^\circ C$

**THERMAL DATA**

$R_{thj-case}$	Thermal Resistance Junction-case	Max	1.76	$^{\circ}C/W$
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**ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25^{\circ}C$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CER}$	Collector Cutoff Current ( $R_{BE} = 10\Omega$ )	$V_{CE} = V_{CEV}$ $V_{CE} = V_{CEV}$ $T_C = 100^{\circ}C$			0.2 1.5	mA mA
$I_{CEV}$	Collector Cutoff Current	$V_{CE} = V_{CEV}$ $V_{BE} = -1.5V$ $V_{CE} = V_{CEV}$ $V_{BE} = -1.5V$ $T_C = 100^{\circ}C$			0.2 1.5	mA mA
$I_{EBO}$	Emitter Cutoff Current ( $I_C = 0$ )	$V_{EB} = 5V$			1	mA
$V_{CEO(sus)}^*$	Collector Emitter Sustaining Voltage	$I_C = 0.2A$ $L = 25mH$	450			V
$V_{EBO}$	Emitter-base Voltage ( $I_C = 0$ )	$I_E = 50mA$	7			V
$V_{CE(sat)}^*$	Collector-emitter Saturation Voltage	$I_C = 5A$ $I_B = 1A$ $I_C = 5A$ $I_B = 1A$ $T_J = 100^{\circ}C$			1.2 2	V V
$V_{BE(sat)}^*$	Base-emitter Saturation Voltage	$I_C = 5A$ $I_B = 1A$ $I_C = 5A$ $I_B = 1A$ $T_J = 100^{\circ}C$			1.3 1.3	V V
$di_c/dt$	Rated of Rise of on-state Collector Current	$V_{CC} = 300V$ $R_C = 0$ $I_{B1} = 1.5A$ $t_D = 3\mu s$ $T_J = 100^{\circ}C$ See fig. 1	45			A/ $\mu s$

**INDUCTIVE LOAD**

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$t_s$	Storage Time	$V_{CC} = 400V$ $V_{clamp} = 450V$			3	$\mu s$
$t_f$	Fall Time	$I_C = 5A$ $I_B = 1A$			0.4	$\mu s$
$t_c$	Crossover Time	$V_{BB} = -5V$ $R_{BB} = 2.5\Omega$ $L_C = 4mH$ $T_J = 100^{\circ}C$ See fig.2			0.7	$\mu s$
$V_{CEW}$	Maximum Collector Emitter Voltage without Snubber	$V_{CC} = 50V$ $I_{CWoff} = 7.5A$ $V_{BB} = -5V$ $I_{B1} = 1A$ $L_C = 0.33mH$ $R_{BB} = 2.5\Omega$ $T_J = 125^{\circ}C$ See fig.2	450			V

Figure 1 : Turn-on Switching Characteristics of the Transistor.

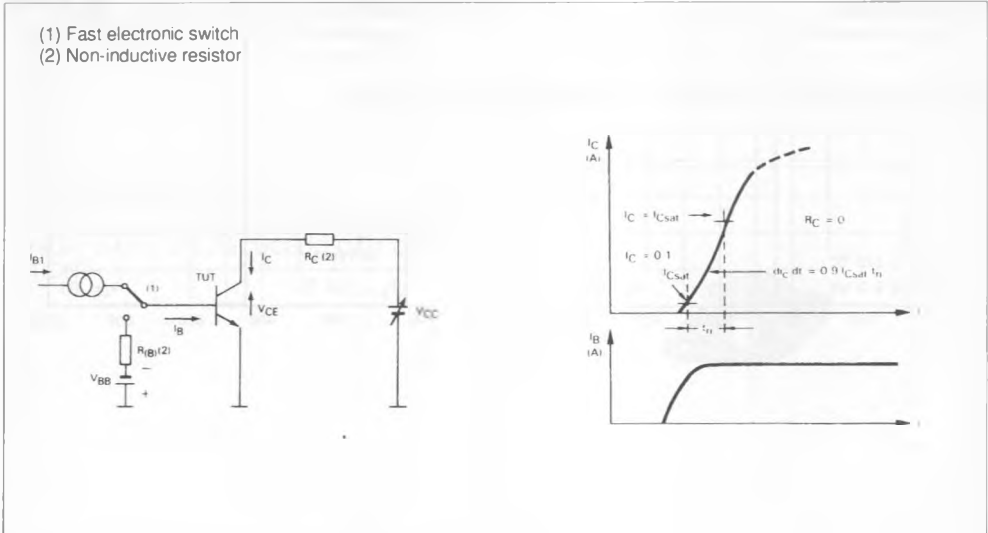
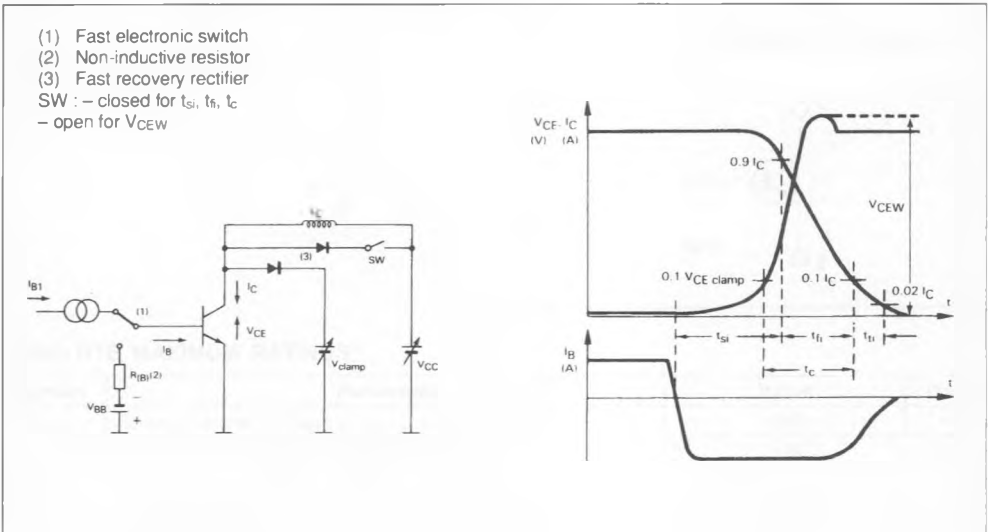
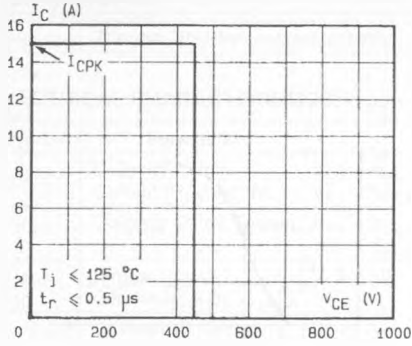


Figure 2 : Turn-off Switching Characteristics of the Transistor.



Forward Biased Safe Operating Area (FBSOA).



Reverse Biased Safe Operating Area (RBSOA).

